

**VHF/UHF NPN Epitaxial Planar Transistor**

# BTNH10N3

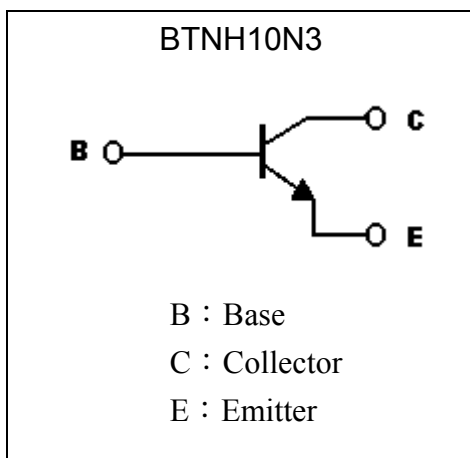
## Description

The BTNH10N3 is designed for use in VHF & UHF oscillators and VHF mixer in tuner of a TV receiver.

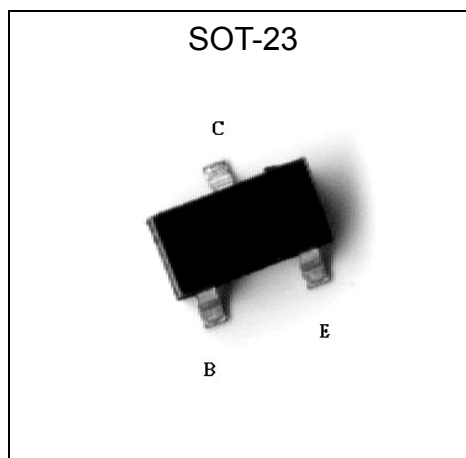
## Features

- High transition frequency.
- Very low capacitance.
- Small  $R_{bb'}$ - $C_c$  and high current gain.
- Pb-free package

## Symbol



## Outline



## Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	$V_{CBO}$	30	V
Collector-Emitter Voltage	$V_{CEO}$	25	V
Emitter-Base Voltage	$V_{EBO}$	3	V
Collector Current	$I_C$	50	mA
Power Dissipation	$P_d$	225	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature	$T_{stg}$	-55~+150	°C



Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV <sub>CB0</sub>	30	-	-	V	I <sub>C</sub> =100μA
BV <sub>CEO</sub>	25	-	-	V	I <sub>C</sub> =1mA
BV <sub>EBO</sub>	3	-	-	V	I <sub>C</sub> =10μA
I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> =25V
I <sub>EBO</sub>	-	-	100	nA	V <sub>EB</sub> =2V
*V <sub>CE(sat)</sub>	-	-	0.5	V	I <sub>C</sub> =4mA, I <sub>B</sub> =0.4mA
*V <sub>BE(on)</sub>	-	-	0.95	V	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA
*h <sub>FE</sub>	52	-	270	-	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA
f <sub>T</sub>	650	1000	-	MHz	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA, f=100MHz
C <sub>ob</sub>	-	-	0.7	pF	V <sub>CB</sub> =10V, I <sub>E</sub> =0A, f=1MHz
R <sub>bb</sub> '-C <sub>c</sub>	-	-	9	ps	V <sub>CB</sub> =10V, I <sub>C</sub> =4mA, f=31.8MHz

\*Pulse Test : Pulse Width ≤380μs, Duty Cycle≤2%

Classification Of hFE

Rank	K	P	Q
Range	52~120	82~180	120~270

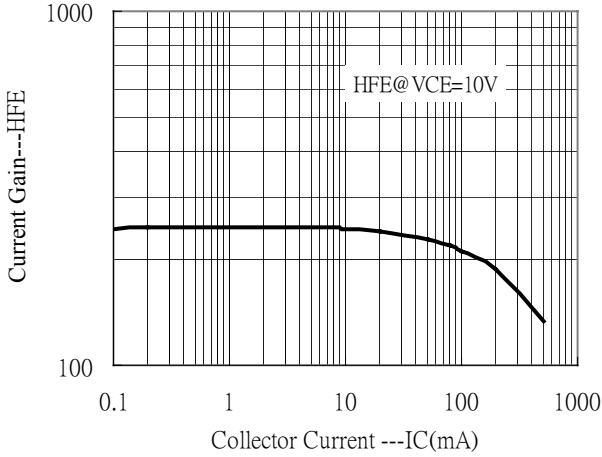
Ordering Information

Device	Package	Shipping	Marking
BTNH10N3	SOT-23 (Pb-free)	3000 pcs / Tape & Reel	3E

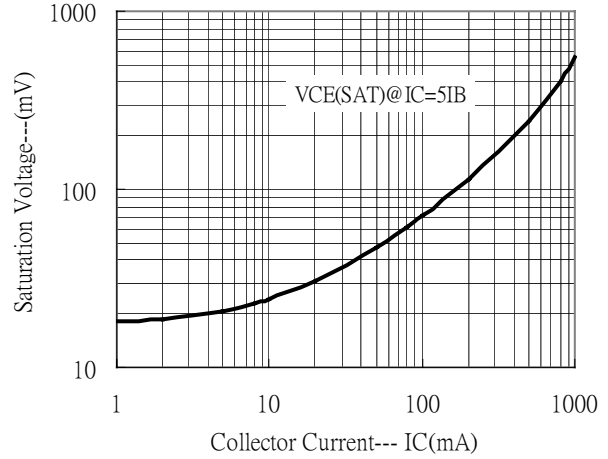


### Characteristic Curves

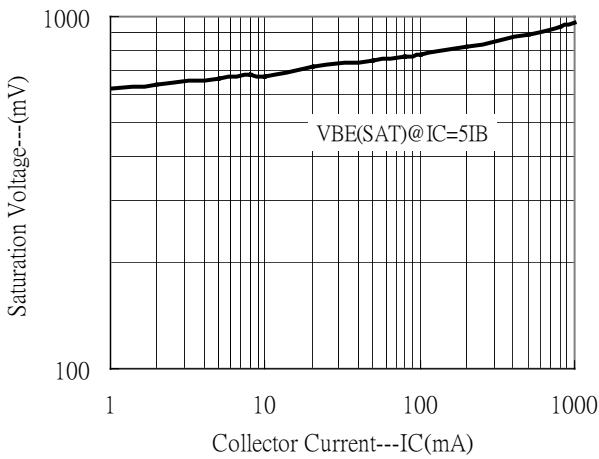
Current Gain vs Collector Current



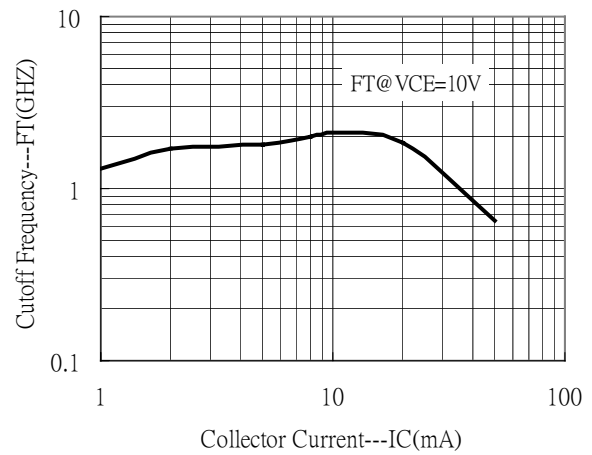
Saturation Voltage vs Collector Current



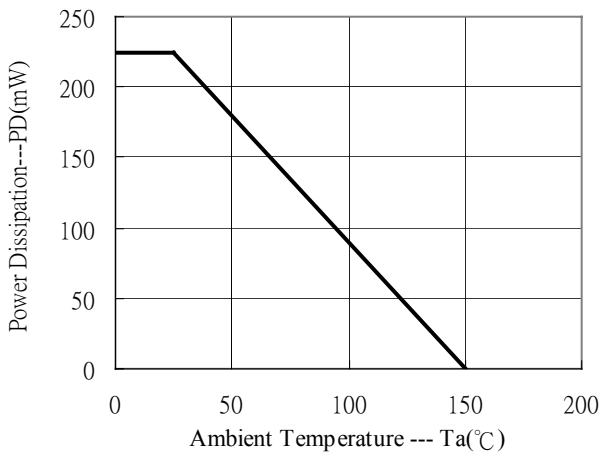
Saturation Voltage vs Collector Current



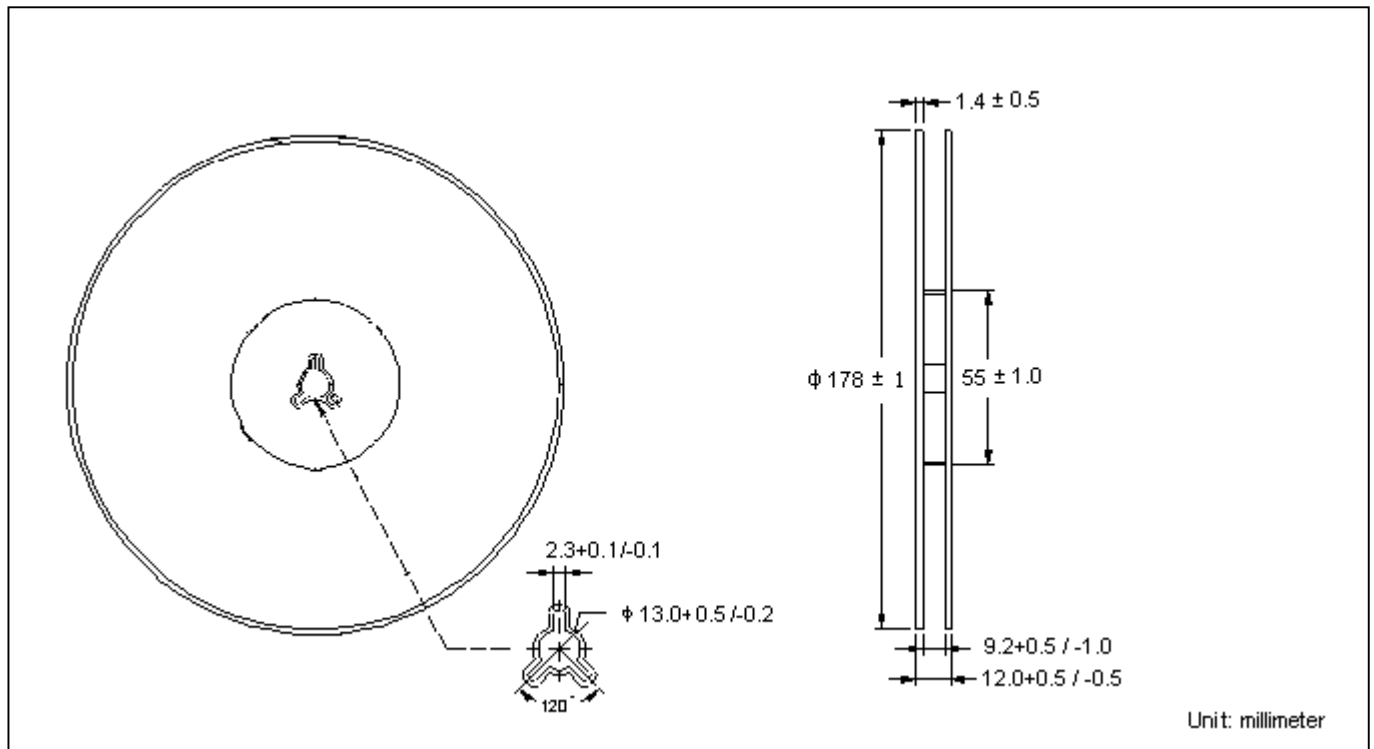
Cutoff Frequency vs Collector Current



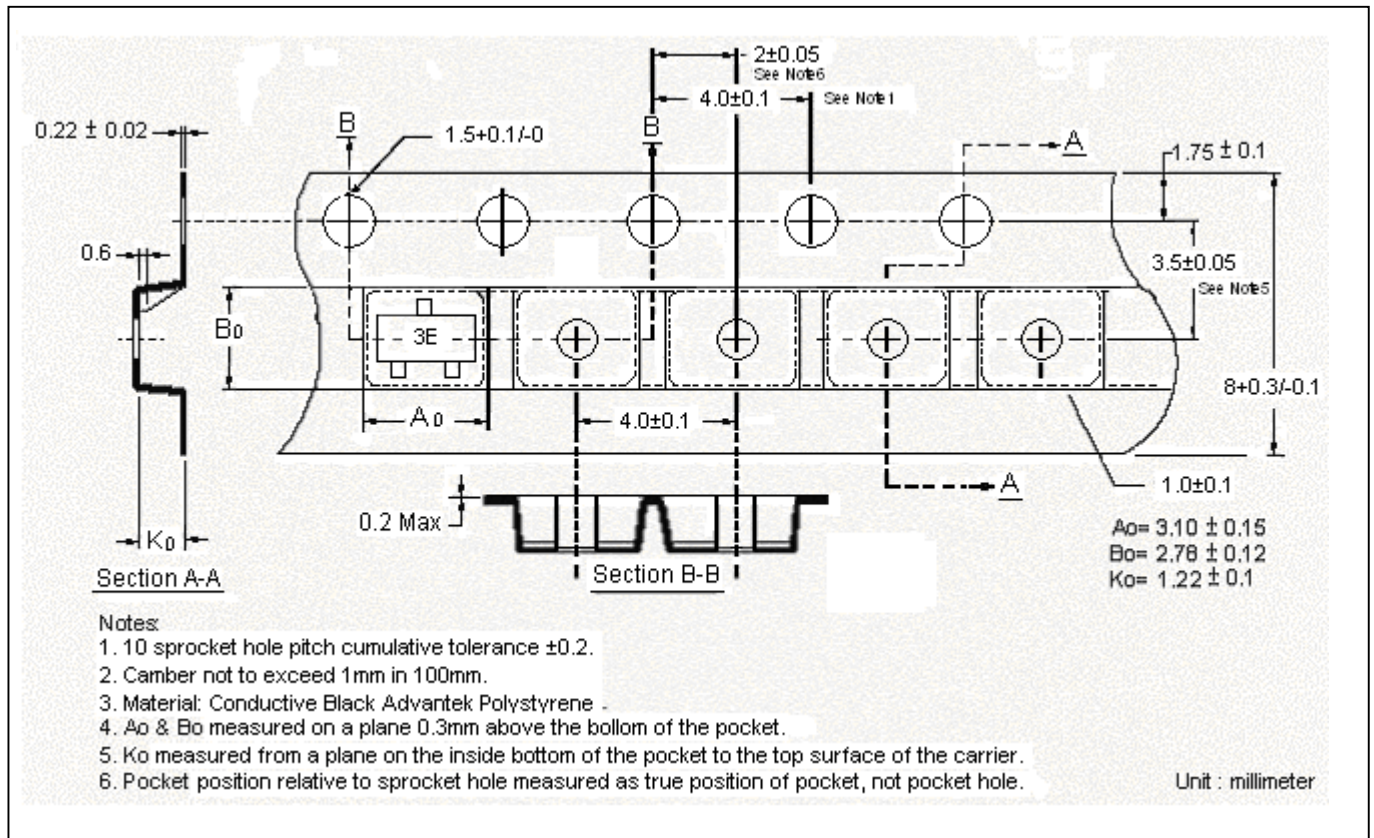
Power Derating Curve



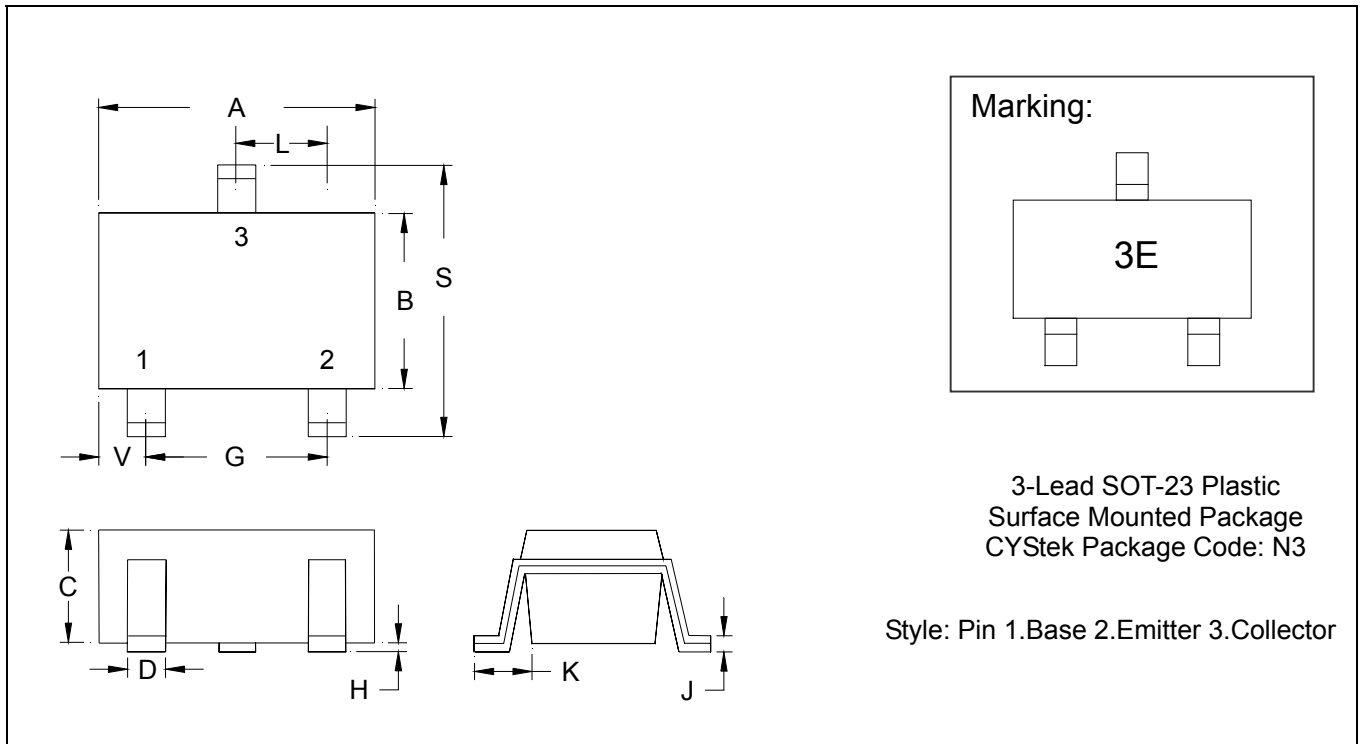
### Reel Dimension



### Carrier Tape Dimension



**SOT-23 Dimension**



\*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0034	0.0070	0.085	0.177
B	0.0472	0.0630	1.20	1.60	K	0.0128	0.0266	0.32	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1083	2.10	2.75
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0005	0.0040	0.013	0.10					

- Notes:**
- Controlling dimension: millimeters.
  - Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
  - If there is any question with packing specification or packing method, please contact your local CYStek sales office.

**Material:**

- Lead: 42 Alloy ; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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